

**Schottky Diode** 

## DSA30C45PB

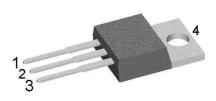
#### preliminary

V <sub>RRM</sub>	=	45 V
I <sub>FAV</sub>	<i>=</i> 2x	15 A
V_	=	0.63 V

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

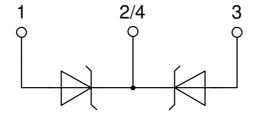
Part number

DSA30C45PB



Backside: cathode

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#### Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
  Low voltage peaks for reduced
- protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

#### Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

#### **Disclaimer Notice**

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IXYS reserves the right to change limits, conditions and dimensions.



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preliminary

Schottky	/				Rating	S	
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse block	ng voltage	$T_{VJ} = 25^{\circ}C$			45	V
V <sub>RRM</sub>	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			45	V
l <sub>R</sub>	reverse current, drain current	$V_{R} = 45 V$	$T_{VJ} = 25^{\circ}C$			250	μA
		$V_{R} = 45 V$	$T_{vJ} = 125^{\circ}C$			2.5	mA
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 15 A	$T_{vJ} = 25^{\circ}C$			0.75	V
		$I_{F} = 30 \text{ A}$				0.91	V
		I <sub>F</sub> = 15 A	T <sub>vJ</sub> = 125°C			0.63	V
		$I_{F} = 30 \text{ A}$				0.79	V
I FAV	average forward current	T <sub>c</sub> = 155°C	T <sub>vJ</sub> = 175°C			15	A
		rectangular d = 0.5					
V <sub>F0</sub>	threshold voltage		T <sub>vJ</sub> = 175°C			0.42	V
r <sub>F</sub>	slope resistance } for power lo	oss calculation only				9.9	mΩ
<b>R</b> <sub>thJC</sub>	thermal resistance junction to cas	е				1.75	K/W
R <sub>thCH</sub>	thermal resistance case to heatsir	nk			0.5		K/W
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			85	W
	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_{R} = 0 V$	$T_{vJ} = 45^{\circ}C$			340	A
CJ	junction capacitance	$V_{B} = 5V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		497		pF

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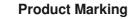
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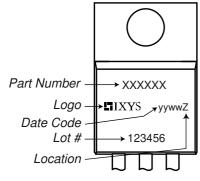


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Package TO-220				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
	RMS current	per terminal n			35	Α	
T <sub>vj</sub>	virtual junction temperature		-55		175	°C	
T <sub>op</sub>	operation temperature		-55		150	°C	
T <sub>stg</sub>	storage temperature		-55		150	°C	
Weight				2		g	
M <sub>D</sub>	mounting torque		0.4		0.6	Nm	
F <sub>c</sub>	mounting force with clip		20		60	Ν	





### Part description

- D = Diode
- S = Schottky Diode A = low VF
- 30 = Current Rating [A]
- C = Common Cathode
- 45 = Reverse Voltage [V]
- PB = TO-220AB (3)

[	Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
	Standard	DSA30C45PB	DSA30C45PB	Tube	50	503934

Similar Part	Package	Voltage class
DSA30C45PC	TO-263AB (D2Pak) (2)	45
DSA30C45HB	TO-247AD (3)	45

Equiva	lent Circuits for	Simulation	* on die level	$T_{vJ} = 175^{\circ}C$
	)[R₀_]-	Schottky		
V <sub>0 max</sub>	threshold voltage	0.42		V
$\mathbf{R}_{0 \max}$	slope resistance *	6.7		mΩ

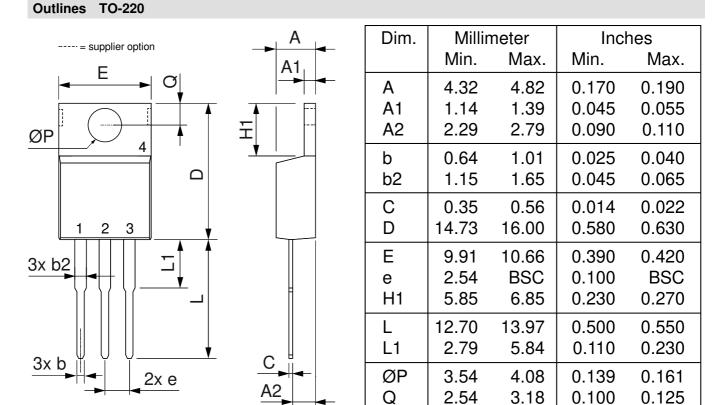
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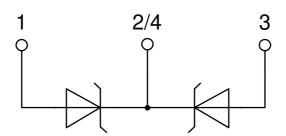
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